Vishay Semiconductors

Standard Recovery Diodes (Stud Version), 70 A

FEATURES

- · High surge current capability
- · Designed for a wide range of applications
- · Stud cathode and stud anode version
- · Leaded version available
- Types up to 1600 V V_{RBM}
- · Compliant to RoHS directive 2002/95/EC
- · Designed and qualified for industrial level

TYPICAL APPLICATIONS

- Converters
- Power supplies
- · Machine tool controls
- · Battery charges

MAJOR BATINGS AND CHARACTERISTICS

70 A

| MAUON NATINGS AND CHANACTERISTICS | | | | | |
|-----------------------------------|-----------------|--------------|-------------|--------------------|--|
| PARAMETER | TEST CONDITIONS | 70H | | | |
| PARAMETER | | 10 TO 120 | 140/160 | UNITS | |
| I= | | 70 | 70 | А | |
| I _{F(AV)} | T _C | 140 | 110 | °C | |
| I _{F(RMS)} | | 11 | 0 | А | |
| I | 50 Hz | 1200 | | A | |
| IFSM | 60 Hz | 12 | 50 | A . | |
| l ² t | 50 Hz | 7100 6450 | | – A ² s | |
| 1-1 | 60 Hz | | | A-S | |
| V _{RRM} | Range | 100 to 1200 | 1400/1600 | V | |
| T,I | | - 65 to 180 | - 65 to 150 | °C | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | |
|-----------------|-----------------|---|---|---|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | V _{R(BR)} , MINIMUM AVALANCHE VOLTAGE V | I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA |
| | 10 | 100 | 200 | 200 | |
| | 20 | 200 | 300 | 300 | 15 |
| | 40 | 400 | 500 | 500 | |
| | 60 | 600 | 720 | 725 | |
| 70HF(R) | 80 | 800 | 960 | 950 | 9 |
| | 100 | 1000 | 1200 | 1150 | 9 |
| | 120 | 1200 | 1440 | 1350 | |
| | 140 | 1400 | 1650 | 1550 | 4.5 |
| | 160 | 1600 | 1900 | 1750 | |

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PRODUCT SUMMARY

 $\mathsf{I}_{\mathsf{F}(\mathsf{AV})}$

DO-203AB (DO-5)

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| FORWARD CONDUCTIO | N | | | | | | | |
|---|---------------------|---|-------------------------------------|--|------|-------|------------------|--|
| PARAMETER | SYMBOL | OL TEST CONDITIONS | | 70HF(R) 10 TO 120 140/160 | | UNITS | | |
| Maximum average forward current | l=(m) | 180° condu | | | 70 | | A | |
| at case temperature | I _{F(AV)} | 100 contau | 180° conduction, half sine wave | | 140 | 110 | °C | |
| Maximum RMS forward current | I _{F(RMS)} | | | | 110 | | Α | |
| | | t = 10 ms | No voltage | | 1200 | | - A | |
| Maximum peak, one cycle forward, | | t = 8.3 ms | reapplied | | 1250 | | | |
| non-repetitive surge current | IFSM | t = 10 ms | 100 % V _{BBM} | | 1000 | | | |
| | | t = 8.3 ms | reapplied | Sinusoidal half wave, | 1(| 050 | 1 | |
| | l ² t | t = 10 ms | No voltage | initial T _J = T _J maximum | 7100 | | A ² s | |
| Maring 12t fan fraing | | t = 8.3 ms | reapplied | | 6450 | | | |
| Maximum I ² t for fusing | | t = 10 ms | 100 % V _{RRM} reapplied | | 5000 | | | |
| | | t = 8.3 ms | | | 4 | 550 | 1 1 | |
| Maximum I ² √t for fusing | l²√t | t = 0.1 ms to 10 ms, no voltage reapplied | | 71 | 000 | A²√s | | |
| Low level value of threshold voltage | V _{F(TO)1} | $(16.7 \% x \pi x I_{F(AV)} < I < \pi x I_{F(AV)}), T_J = T_J maximum$ | | 0 | .79 | | | |
| High level value of threshold voltage | V _{F(TO)2} | $(I > \pi \times I_{F(AV)}), T_J = T_J$ maximum | | 1.00 | | V | | |
| Low level value of forward slope resistance | r _{f1} | $(16.7 \% \text{ x } \pi \text{ x } _{F(AV)} < l < \pi \text{ x } _{F(AV)}), T_J = T_J \text{ maximum}$ | | 2.33 | | mΩ | | |
| High level value of forward slope resistance | r _{f2} | $(I > \pi x I_{F(AV)}), T_J = T_J maximum$ | | 1.53 | | | | |
| Maximum forward voltage drop | V _{FM} | $I_{pk} = 220 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu\text{s}$ rectangular wave 1.35 | | 1.35 | 1.46 | V | | |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|---|-----------------------------------|--|-------------|--------------|---------------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | 70HF(R) | | UNITS | |
| FARAMETER | STMBOL | TEST CONDITIONS | 10 TO 120 | 140/160 | 01113 | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | - 65 to 180 | - 65 to 150 | °C | |
| Maximum thermal resistance, junction to case R _{thJC} | | DC operation | 0.45 | | K/W | |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth, flat and greased 0.25 | | .25 | rv VV | |
| | | Not lubricated thread, tighting on nut ⁽¹⁾ | 3.4 (30) | | N ⋅ m (lbf ⋅ in) | |
| Maximum allowable mounting | | Lubricated thread, tighting on nut ⁽¹⁾ | 2.3 (20) | | | |
| torque (+ 0 %, - 10 %) | | Not lubricated thread, tighting on hexagon (2)4.2 (37)Lubricated thread, tighting on hexagon (2)3.2 (28) | | | | |
| | | | | | | |
| Approximato woight | | | | 17 | g | |
| Approximate weight | | | (|).6 | oz. | |
| Case style | | See dimensions - link at the end of datasheet DO-203AE | | D-203AB (DO- | 5) | |

Notes

⁽¹⁾ Recommended for pass-through holes

⁽²⁾ Recommended for holed threaded heatsinks



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| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS | UNITS | | |
|------------------|-----------------------|------------------------|---------------------|-------|--|--|
| 180° | 0.08 | 0.06 | | | | |
| 120° | 0.10 | 0.11 | | | | |
| 90° | 0.13 | 0.14 | $T_J = T_J maximum$ | K/W | | |
| 60° | 0.19 | 0.20 | | | | |
| 30° | 0.30 | 0.30 | | | | |

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

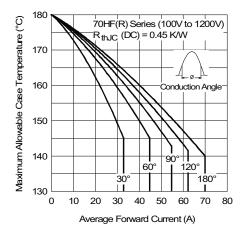


Fig. 1 - Current Ratings Characteristics

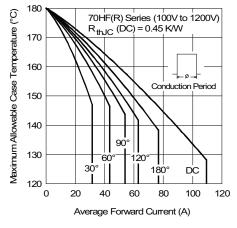


Fig. 2 - Current Ratings Characteristics

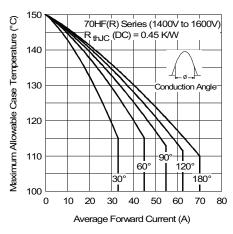


Fig. 3 - Current Ratings Characteristics

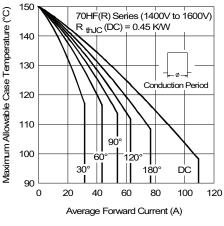


Fig. 4 - Current Ratings Characteristics

Vishay Semiconductors

Standard Recovery Diodes (Stud Version), 70 A



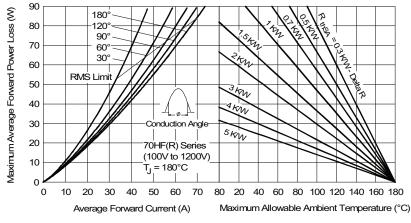


Fig. 5 - Forward Power Loss Characteristics

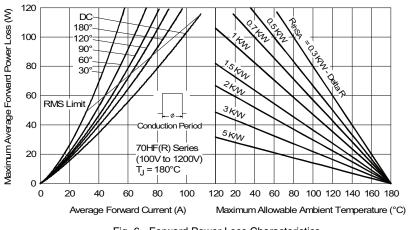


Fig. 6 - Forward Power Loss Characteristics

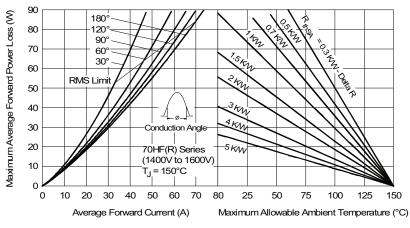
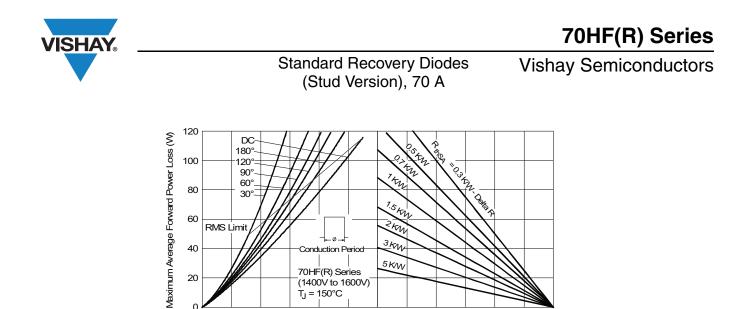


Fig. 7 - Forward Power Loss Characteristics



120

Fig. 8 - Forward Power Loss Characteristics

25

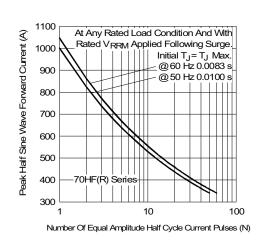
50

75

Maximum Allowable Ambient Temperature (°C)

100

125



0

0

20

60

Average Forward Current (A)

80

100

40

Fig. 9 - Maximum Non-Repetitive Surge Current

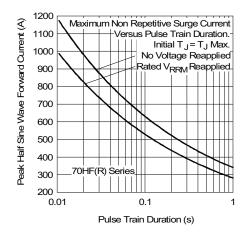
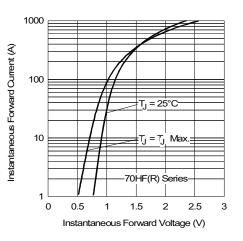


Fig. 10 - Maximum Non-Repetitive Surge Current



150

Fig. 11 - Forward Voltage Drop Characteristics

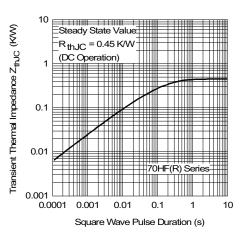
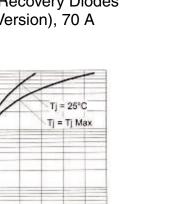


Fig. 12 - Thermal Impedance Z_{thJC} Characteristics

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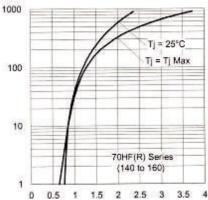
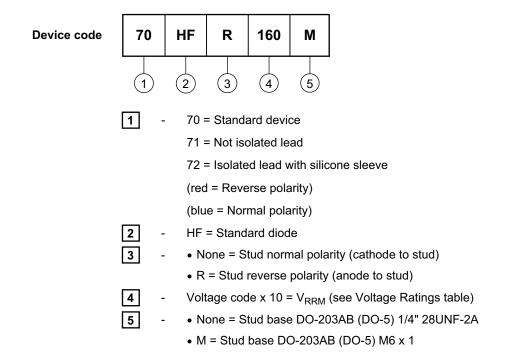


Fig. 13 - Forward Voltage Drop Characteristics

ORDERING INFORMATION TABLE

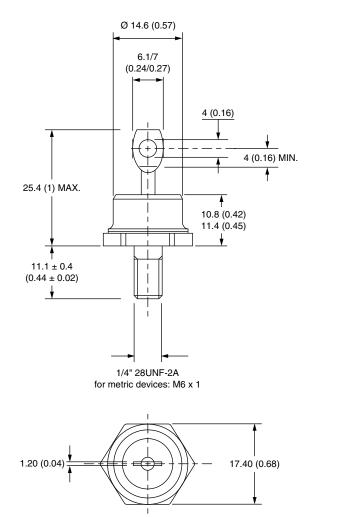


| LINKS TO RELATED DOCUMENTS | | |
|----------------------------|--------------------------|--|
| Dimensions | www.vishay.com/doc?95343 | |

Vishay Semiconductors

DO-203AB (DO-5) for 70HF(R) and 71HF(R) Series

DIMENSIONS FOR 70HF(R) SERIES in millimeters (inches)



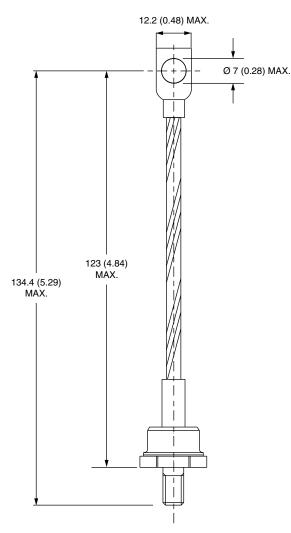


Vishay Semiconductors

DO-203AB (DO-5) for 70HF(R) and 71HF(R) Series



DIMENSIONS FOR 71HF(R) SERIES in millimeters (inches)





Vishay

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